

INA254 80V、高電圧、 $\pm 75A$ 高精度シャント内蔵、双方向、ゼロドリフト電流シャントモニタ

1 特長

- 高精度 $400\mu\Omega$ シャント抵抗を内蔵
 - 25°C で連続電流 $\pm 75A$
 - $-40^\circ\text{C} \sim +85^\circ\text{C}$ で連続電流 $\pm 50A$
 - シャント抵抗の公差: 0.5% (最大値)
 - 低いドリフト: $10\text{ppm}/^\circ\text{C}$ ($0^\circ\text{C} \sim 125^\circ\text{C}$)
 - 低いインダクタンス: 2nH
- 高い精度
 - システム・ゲイン誤差: 0.5% (最大値)
 - システム・ゲイン・ドリフト: $45\text{ppm}/^\circ\text{C}$ (最大値)
 - 入力オフセット電流: $\pm 62.5\text{mA}$ (最大値)
 - 入力オフセット・ドリフト: $625\mu\text{A}/^\circ\text{C}$ (最大値)
 - DC CMRR > 120dB
 - 50kHz において 90dB の AC CMRR
- 強化された PWM 除去
- 広いコモン・モード電圧範囲: $-4V \sim +80V$
- 利用可能なゲイン: $20\text{mV}/A$ 、 $40\text{mV}/A$ 、 $75\text{mV}/A$

2 アプリケーション

- 48V モーター制御
- DC/DC コンバータ
- 医療用コードレス機器
- ソレノイドとアクチュエータ
- リモート I/O リンク制御

3 概要

INA254 は、 $400\mu\Omega$ のシャント抵抗を内蔵した電圧出力の電流センス・アンプです。INA254 は、電源電圧にかかわらず、 $-4V \sim +80V$ の広い同相電圧範囲で双方向の電流を監視するよう設計されています。3 つの固定ゲインを利用可能: $20\text{mV}/A$ 、 $40\text{mV}/A$ 、 $75\text{mV}/A$ 。高精度の抵抗とゼロ・ドリフトのチョップ・アンプを内蔵しているため、校正と等価の測定精度、 $\pm 45\text{ppm}/^\circ\text{C}$ (最大値) という非常に低い温度ドリフト係数、センシング抵抗に最適化されたケルビン・レイアウトが実現されています。

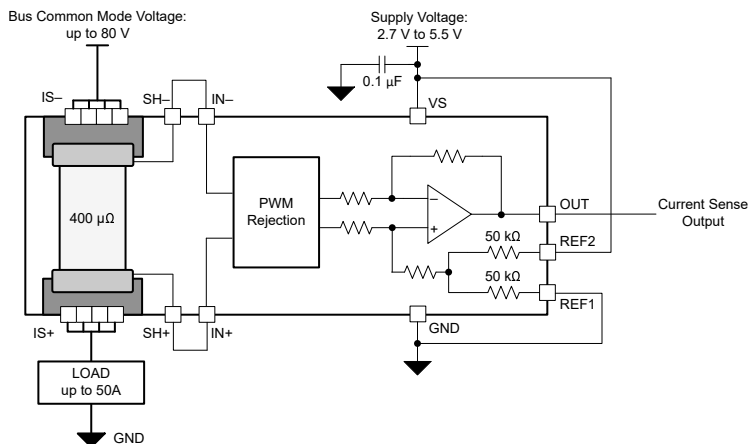
INA254 の設計には、強化された PWM 除去回路が組み込まれており、大きな (dv/dt) 信号を抑制し、リアルタイムで連続的な電流測定が可能です。この測定は、モータ・ドライブ・アプリケーションにおけるインラインの電流測定や、ソレノイドのバルブ制御アプリケーションなどに不可欠なものです。

このデバイスは $2.7V \sim 5.5V$ の単一電源で動作し、消費電流は最大 2.4mA です。どのゲインのバージョンも、拡張動作温度範囲 ($-40^\circ\text{C} \sim +125^\circ\text{C}$) で動作が規定され、24 ピン HTSSOP パッケージで供給されます。

パッケージ情報⁽¹⁾

部品番号	パッケージ	本体サイズ (公称)
INA254	HTSSOP (24)	$9.50\text{mm} \times 4.40\text{mm}$

(1) 利用可能なすべてのパッケージについては、データシートの末尾にあるパッケージ・オプションについての付録を参照してください。



代表的なハイサイド双方向アプリケーション



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4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision * (June 2021) to Revision A (March 2023)	Page
• データシートのステータスを「事前情報」から「量産データ」に変更.....	1
• 「製品情報」表のタイトルを「パッケージ情報」に変更.....	1
• Moved the <i>Power Supply Recommendations</i> and <i>Layout</i> sections to the Application and Implementation section.....	23

5 Device Comparison

表 5-1. Device Comparison

PRODUCT	GAIN (mV/A)
INA254A1	20
INA254A2	40
INA254A3	75

6 Pin Configuration and Functions

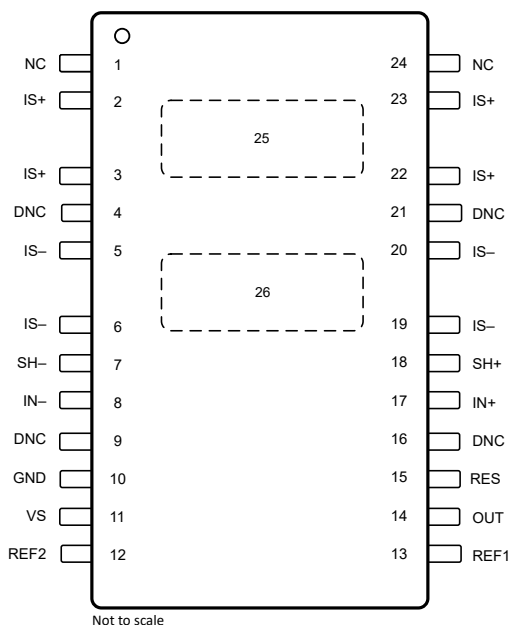


図 6-1. PWA Package 24-Pin HTSSOP Top View

表 6-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
DNC	4, 9, 16, 21	—	Do not connect this pin to any potential; leave this pin floating
GND	10	Ground	Device ground connection
IN+	17	Analog input	Positive input to internal amplifier. Connect to SH+ or external filter network.
IN–	8	Analog input	Negative input to internal amplifier. Connect to SH– or external filter network.
IS+	2, 3, 22, 23, 25	Analog input	Positive connection to internal shunt resistor. Connect to supply for high-side sensing or load ground for low-side sensing.
IS–	5, 6, 19, 20, 26	Analog input	Negative connection to internal shunt resistor. Connect to load for high-side sensing or system ground for low-side sensing.
NC	1, 24	—	No internal connection. Can be left floating, connected to ground or supply. Connecting to IS+ simplifies high current connections to the shunt.
OUT	14	Analog output	Current sense amplifier output.
REF1	13	Analog input	Reference voltage 1. Connect to any voltage between 0 V and VS to support bidirectional or unidirectional operation.
REF2	12	Analog input	Reference voltage 2. Connect to any voltage between 0 V and VS to support bidirectional or unidirectional operation.
RES	15	—	Reserved pin. Connect to GND.
SH+	18	Analog output	Internal shunt positive sense connection. Connect to IN+ or external filter network.
SH–	7	Analog output	Internal shunt negative sense connection. Connect to IN– or external filter network.
VS	11	Power	Device power supply connection, 2.7 V to 5.5 V.

7 仕様

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Supply voltage (V_s)			6	V
Analog input current	Continuous current	–50	50	A
Analog Inputs, V_{IN+} , V_{IN-} ⁽²⁾	Differential (V_{IN+}) - (V_{IN-})	–80	80	V
	Common - mode	GND – 6	90	V
Analog inputs (REF)		GND – 0.3	$V_s + 0.3$	V
Analog outputs (SH+, SH-)	Common - mode	GND – 6	90	V
Analog output (OUT)		GND – 0.3	$V_s + 0.3$	V
T_A	Operating Temperature	–55	150	°C
T_J	Junction temperature		150	°C
T_{stg}	Storage temperature	–65	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) V_{IN+} and V_{IN-} are the voltages at the IN+ and IN– pins, respectively.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{CM}	Common-mode input range	–4		80	V
V_s	Operating supply range	2.7		5.5	V
V_{REF1} , V_{REF2}	Reference voltage range	0		V_s	V
T_A	Ambient temperature	–40		125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		INA254	UNIT
		PWA (HTSSOP)	
		24 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	19.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	2.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance ⁽²⁾	–4.0	°C/W
Ψ_{JT}	Junction-to-top characterization parameter ⁽²⁾	–8.7	°C/W
Ψ_{JB}	Junction-to-board characterization parameter ⁽²⁾	–4.1	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

(2) Negative values result from board temperatures that are higher than the die temperature due to shunt heating.

7.5 Electrical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $I_{\text{SENSE}} = I_{S+} = 0\text{ A}$, $V_{\text{CM}} = 12\text{ V}$, and $V_{\text{REF1}} = V_{\text{REF2}} = V_S / 2$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT						
V_{CM}	Common-mode input range	$V_{\text{IN+}} = -4\text{ V to } 80\text{ V}$, $I_{\text{SENSE}} = 0\text{ A}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$	-4		80	V
CMRR	Common-mode rejection ratio	$V_{\text{IN+}} = -4\text{ V to } 80\text{ V}$, $I_{\text{SENSE}} = 0\text{ A}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$		± 0.5	± 2.5	mA/V
		$f = 50\text{ kHz}$		± 56		
I_{os}	Offset current, input referred	$I_{\text{SENSE}} = 0\text{ A}$			± 62.5	mA
dI_{os}/dT	Offset current drift	$I_{\text{SENSE}} = 0\text{ A}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$			± 0.625	mA/ $^\circ\text{C}$
PSRR	Power supply rejection ratio	$V_S = 2.7\text{ V to } 5.5\text{ V}$, $I_{\text{SENSE}} = 0\text{ A}$			± 25	mA/V
I_B	Input bias current	I_{B+} , I_{B-} , $I_{\text{SENSE}} = 0\text{ A}$		90		μA
INTEGRATED SHUNT RESISTOR						
R_{SHUNT}	Shunt resistance (IN+ to IN-)	Equivalent resistance when used with onboard amplifier	0.398	0.4	0.402	m Ω
		Used as stand-alone resistor		0.4		m Ω
	Package resistance	I_{S+} to I_{S-}		1		m Ω
	Package inductance	I_{S+} to I_{S-}		2		nH
	Resistor temperature coefficient	$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		15		ppm/ $^\circ\text{C}$
		$T_A = -40^\circ\text{C to } 0^\circ\text{C}$		50		
		$T_A = 0^\circ\text{C to } +125^\circ\text{C}$		10		
I_{SENSE}	Maximum Continuous Current	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$			± 50	A
	Shunt short time overload	$I_{\text{SENSE}} = 120\text{ A}$ for 5 seconds		$\pm 0.05\%$		%
	Shunt temperature cycle	$-65^\circ\text{C to } 150^\circ\text{C}$, 500 cycles		± 0.1		%
	Shunt resistance to solder heat	260°C solder, 10 seconds		± 0.1		%
	Shunt high temperature exposure	1000 hours, $T_A = 150^\circ\text{C}$		± 0.3		%
	Shunt cold temperature storage	24 hours, $T_A = -65^\circ\text{C}$		± 0.060		%
OUTPUT						
G	Gain	INA254A1		20		mV/A
		INA254A2		40		mV/A
		INA254A3		75		mV/A
	System Gain error (shunt + amplifier)	$\text{GND} + 50\text{ mV} \leq V_{\text{OUT}} \leq V_S - 200\text{ mV}$, $T_A = 25^\circ\text{C}$		± 0.05	± 0.5	%
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$			± 45	ppm/ $^\circ\text{C}$
	Non-Linearity Error	$\text{GND} + 10\text{ mV} \leq V_{\text{OUT}} \leq V_S - 200\text{ mV}$		± 0.01		%
	Reference Divider Accuracy	$V_{\text{OUT}} = (V_{\text{REF1}} - V_{\text{REF2}}) / 2$ at $I_{\text{SENSE}} = 0\text{ A}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$		± 0.02	± 0.1	%
RVRR	Reference voltage rejection ratio (input - referred)			12.5		mA/V
	Maximum capacitive load	No sustained oscillation		1		nF
VOLTAGE OUTPUT						
	Swing to V_S Power Supply Rail	$R_L = 10\text{ k}\Omega$ to GND, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$	$V_S - 0.05$	$V_S - 0.2$		V
	Swing to Ground	$R_L = 10\text{ k}\Omega$ to GND, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$	$V_{\text{GND}} + 1$	$V_{\text{GND}} + 10$		mV
FREQUENCY RESPONSE						
BW	Bandwidth	All devices, -3dB Bandwidth		350		kHz
		All devices, 2% THD+N		100		kHz

at $T_A = 25\text{ }^{\circ}\text{C}$, $V_S = 5\text{ V}$, $I_{\text{SENSE}} = I_{S+} = 0\text{ A}$, $V_{\text{CM}} = 12\text{ V}$, and $V_{\text{REF1}} = V_{\text{REF2}} = V_S / 2$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Settling time	$V_{\text{IN+}}, V_{\text{IN-}} = 12\text{ V}$, $I_{\text{SENSE}} = 50\text{ A}$ Output settles to 1%		2		μs
SR	Slew Rate			2.4		$\text{V}/\mu\text{s}$
NOISE						
	Current Noise Density			100		$\mu\text{A}/\sqrt{\text{Hz}}$
POWER SUPPLY						
I_Q	Quiescent current			1.8	2.4	mA
		$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$			2.6	mA

7.6 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

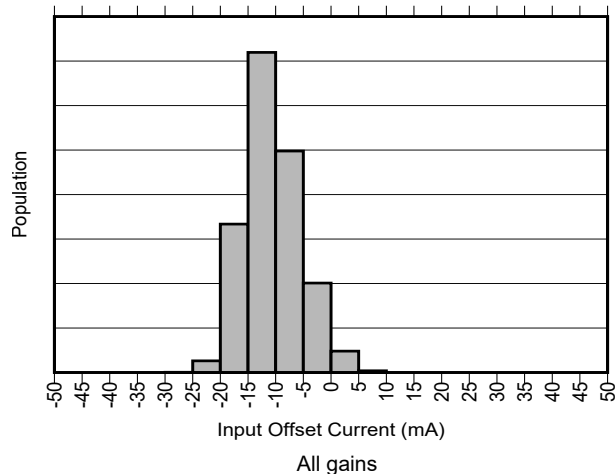


FIG 7-1. Input Offset Current Production Distribution

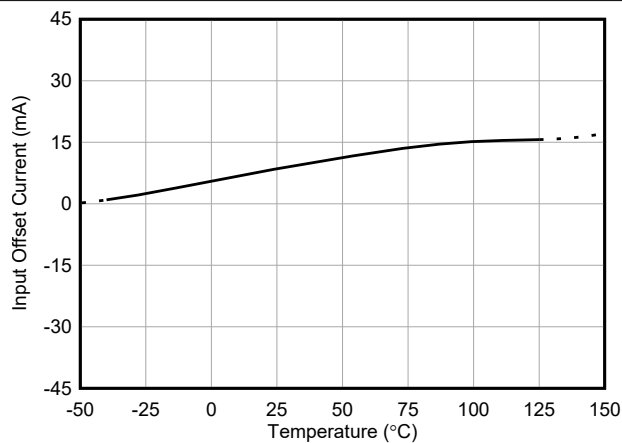


FIG 7-2. Input Offset Current vs Temperature

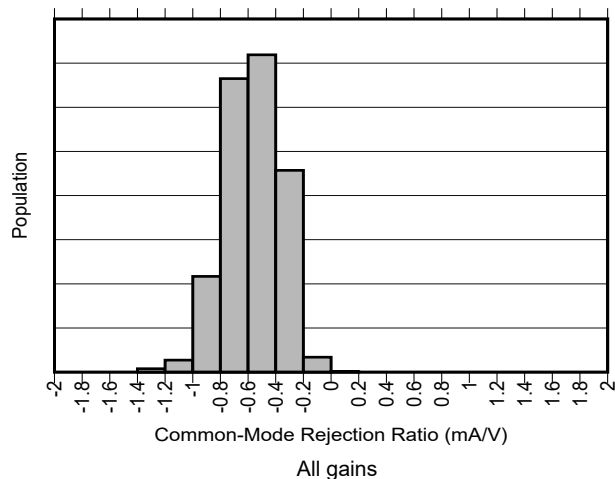


FIG 7-3. Common-Mode Rejection Production Distribution

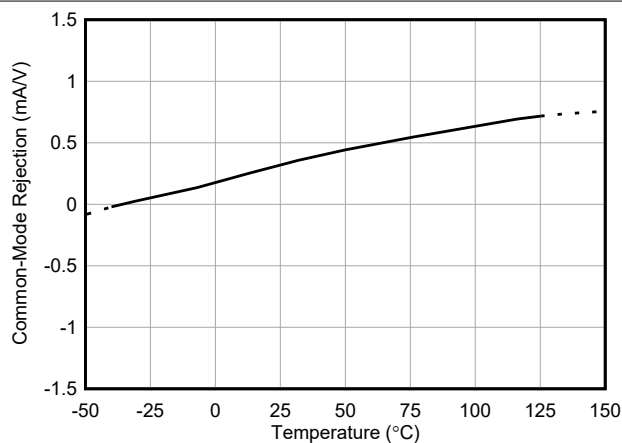


FIG 7-4. Common-Mode Rejection Ratio vs Temperature

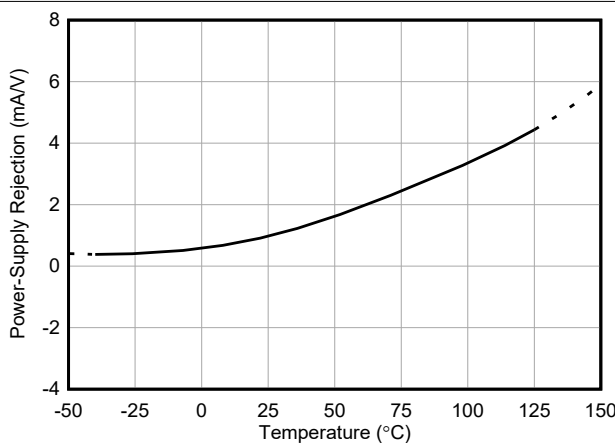


FIG 7-5. Power-Supply Rejection Ratio vs Temperature

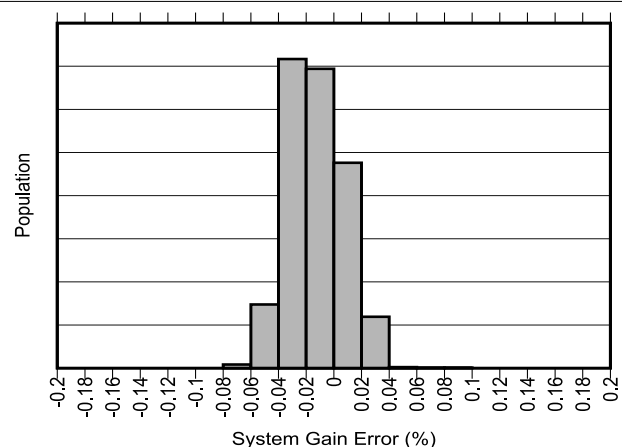
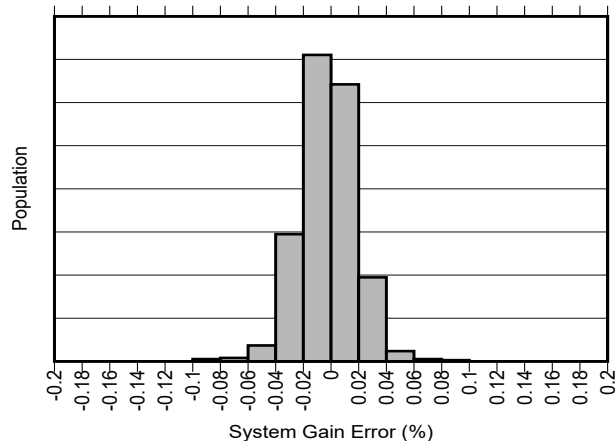


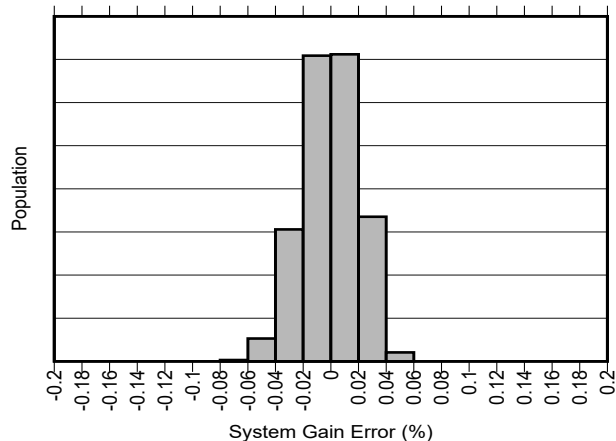
FIG 7-6. Gain Error Production Distribution (INA254A1)

7.6 Typical Characteristics (continued)

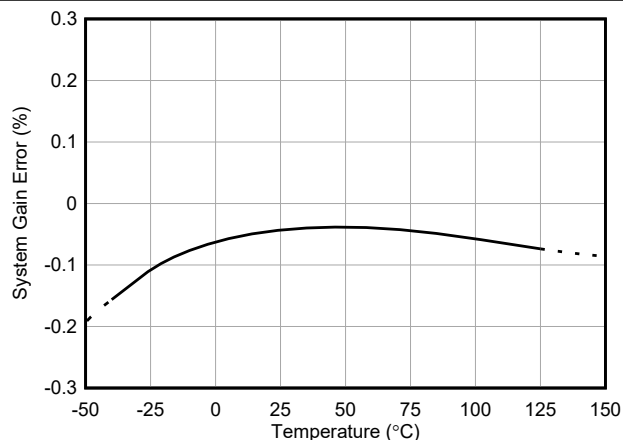
at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)



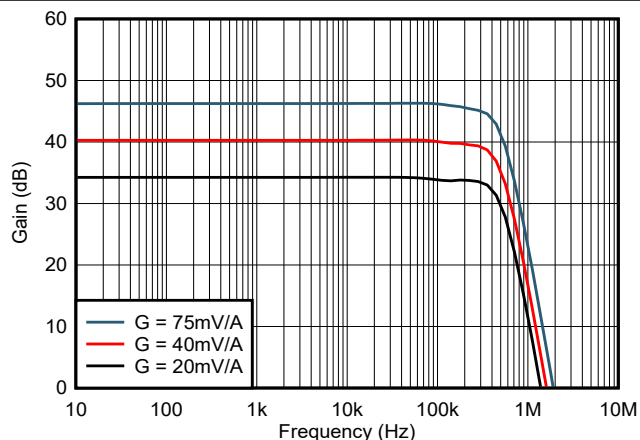
7-7. Gain Error Production Distribution (INA254A2)



7-8. Gain Error Production Distribution (INA254A3)

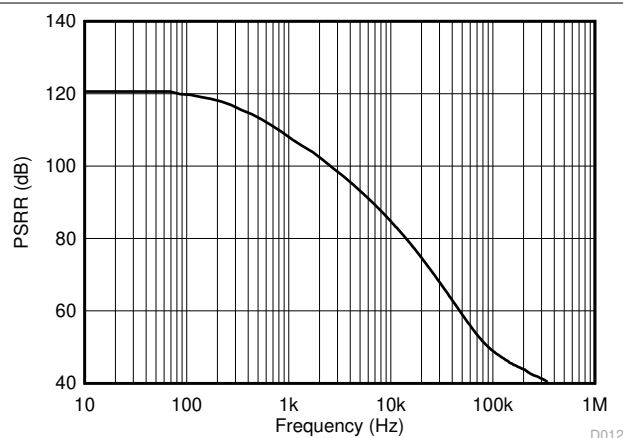


7-9. System Gain Error vs Temperature

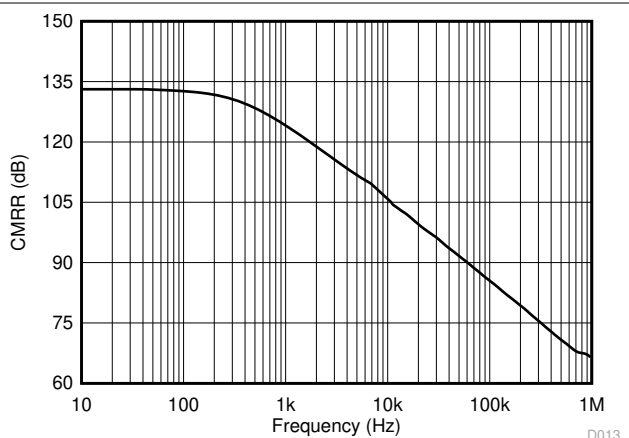


$V_{CM} = 0\text{ V}$, $V_{DIFF} = 10\text{-mV}_{PP}\text{ sine}$

7-10. Amplifier Gain Error vs Frequency



7-11. Power-Supply Rejection Ratio vs Frequency



7-12. Common-Mode Rejection Ratio vs Frequency

7.6 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

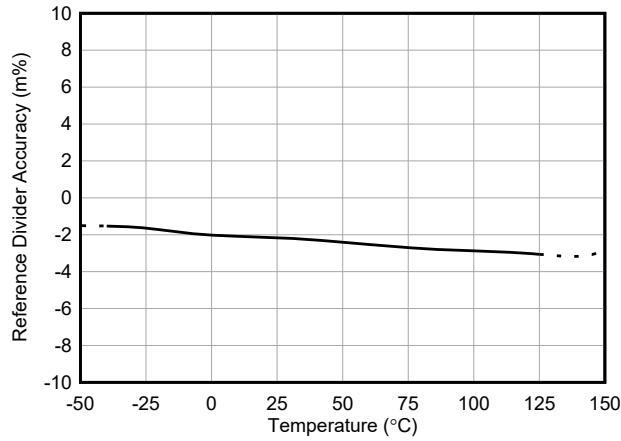


FIG 7-13. Reference Divider Accuracy vs Temperature

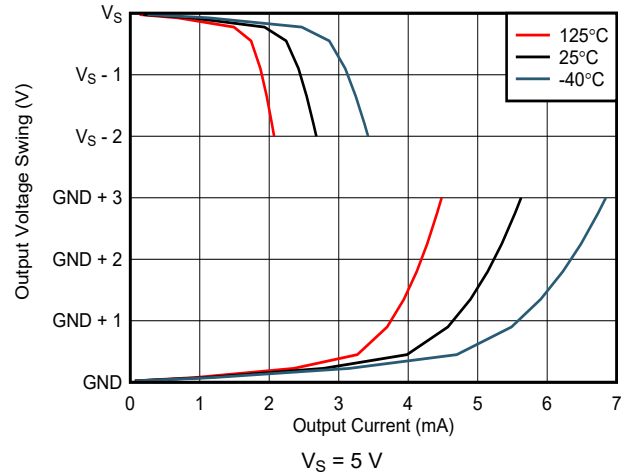


FIG 7-14. Output Voltage Swing vs Output Current

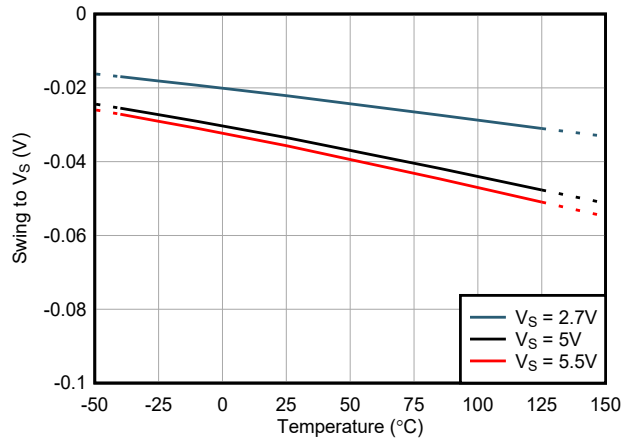


FIG 7-15. Output Voltage Swing High vs Temperature

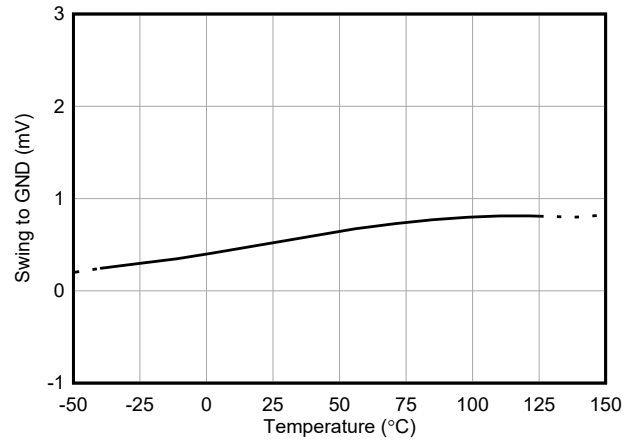


FIG 7-16. Output Voltage Swing Low vs Temperature

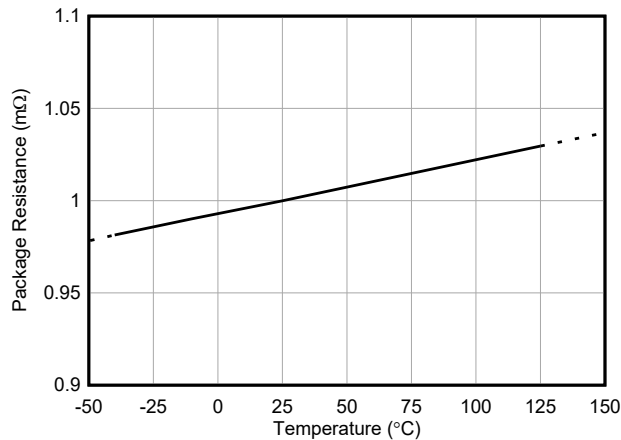


FIG 7-17. Package Resistance vs Temperature

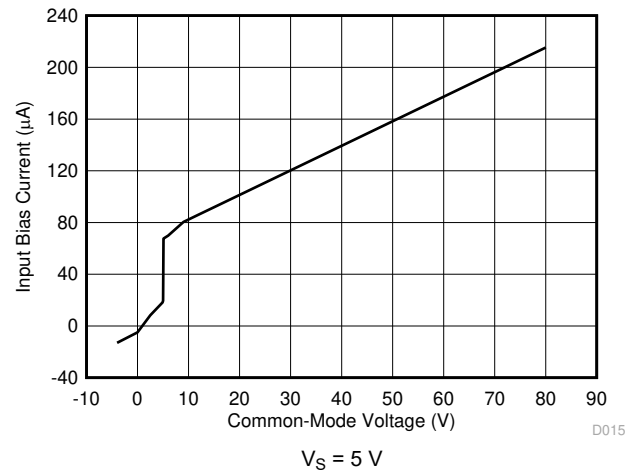


FIG 7-18. Input Bias Current vs Common-Mode Voltage

D015

7.6 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

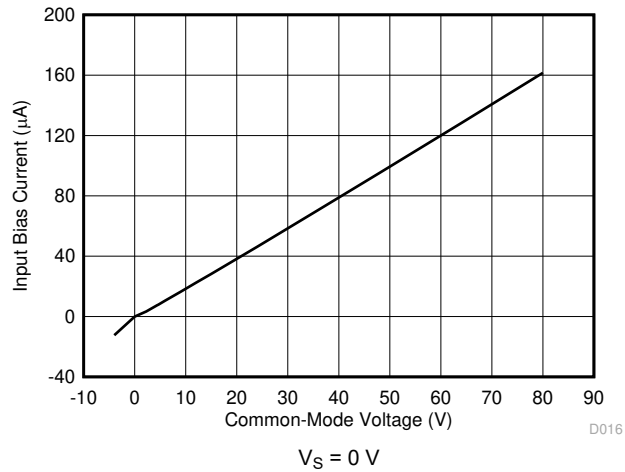


FIG 7-19. Input Bias Current vs Common-Mode Voltage

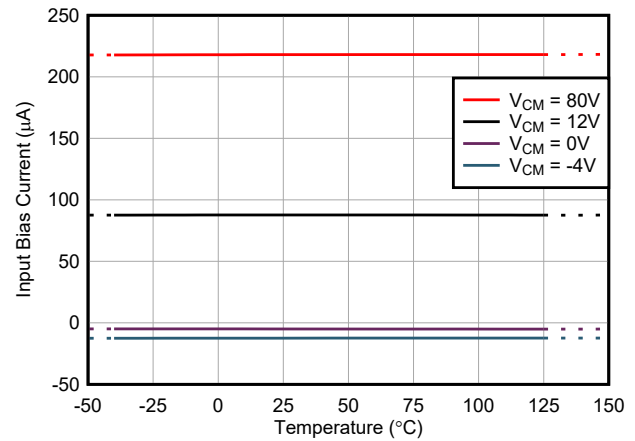


FIG 7-20. Input Bias Current vs Temperature

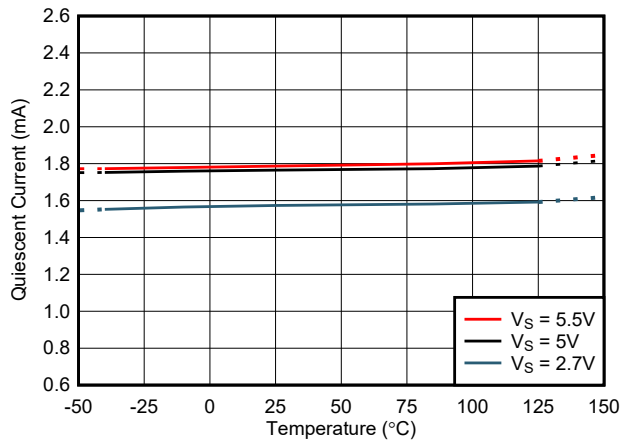


FIG 7-21. Quiescent Current vs Temperature

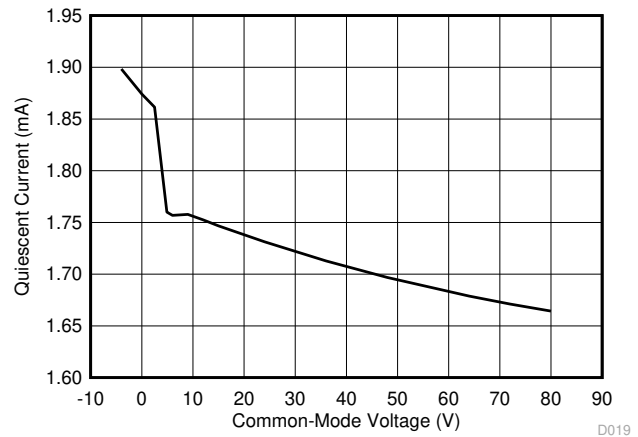


FIG 7-22. Quiescent Current vs Common-Mode Voltage

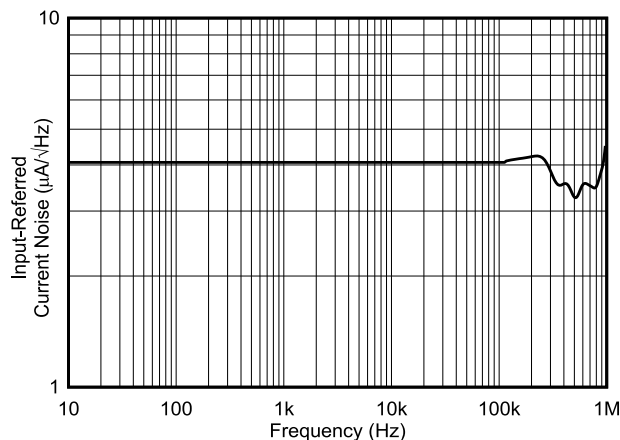


FIG 7-23. INA254A1 Input-Referred Current Noise vs Frequency

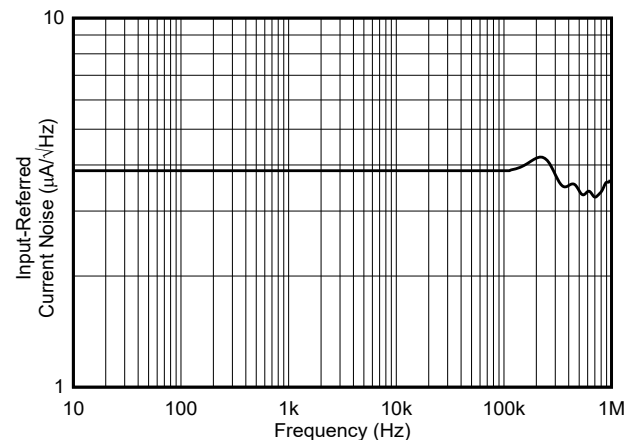
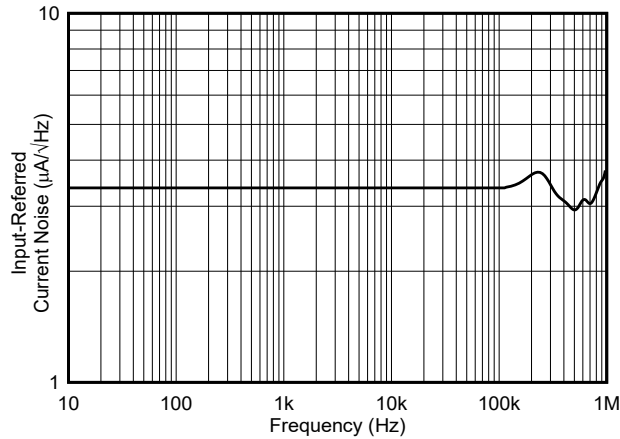


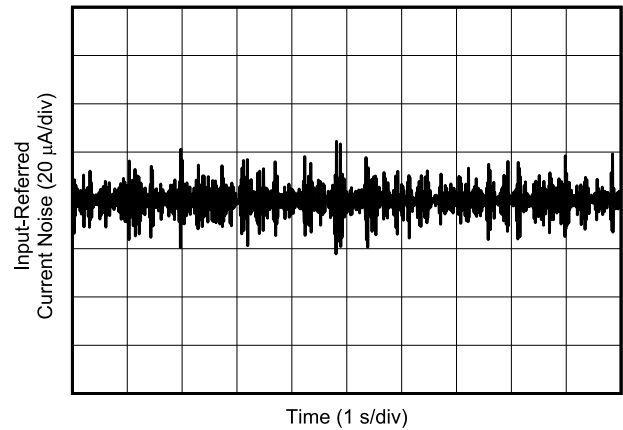
FIG 7-24. INA254A2 Input-Referred Current Noise vs Frequency

7.6 Typical Characteristics (continued)

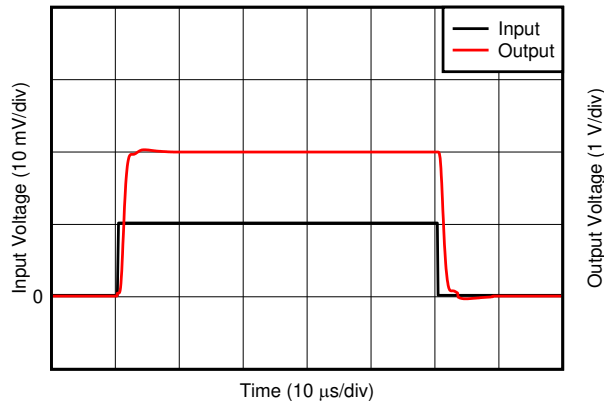
at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)



7-25. INA254A3 Input-Referred Current Noise vs Frequency

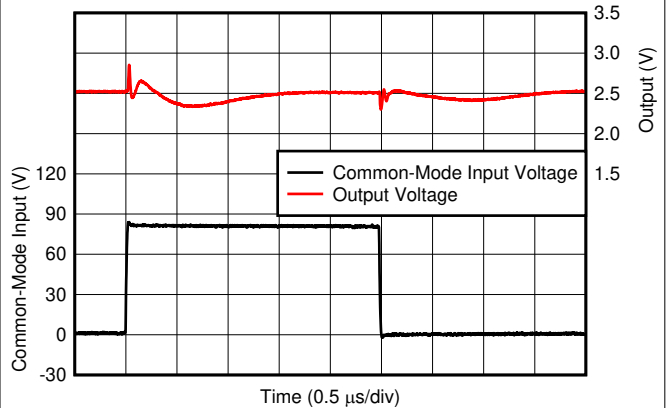


7-26. 0.1-Hz to 10-Hz Current Noise (Referred-to-Input)



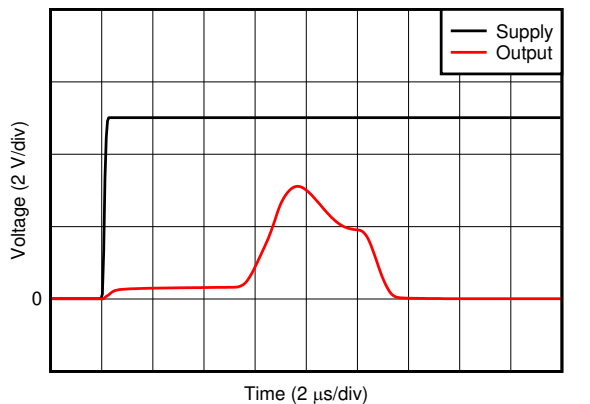
$V_{REF1} = V_{REF2} = 0\text{ V}$, 10-mV_{PP} input step

7-27. Amplifier Step Response

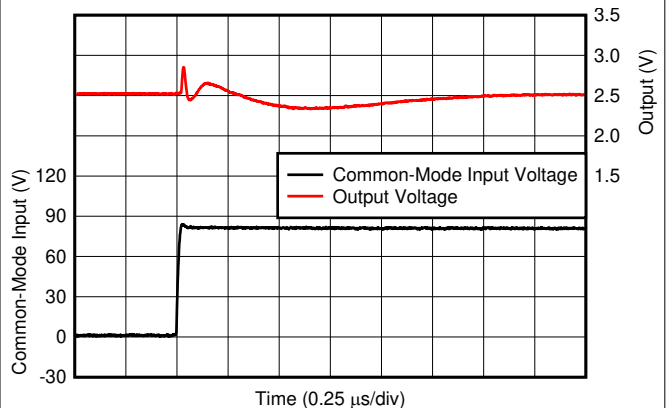


$V_{REF1} = V_{REF2} = 0\text{ V}$

7-28. Common-Mode Transient Response



7-29. Start-Up Response

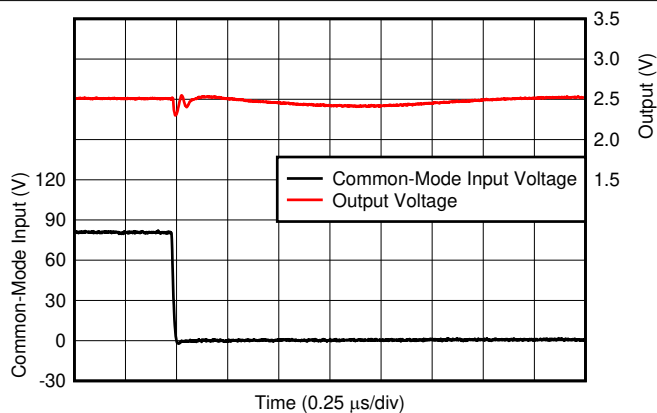


Rising Edge

7-30. Common-Mode Voltage Transient Response

7.6 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)



D028

Falling Edge

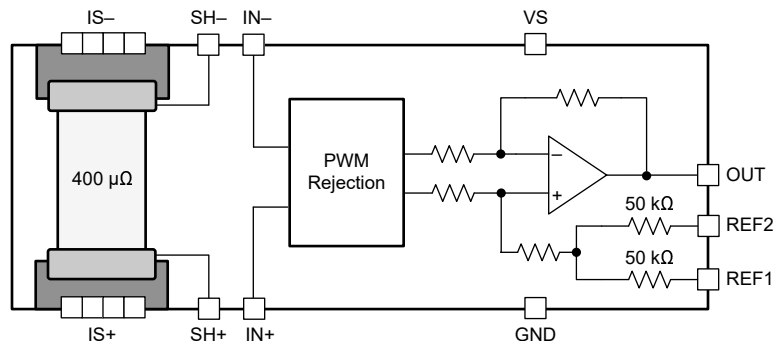
7-31. Common-Mode Voltage Transient Response

8 Detailed Description

8.1 Overview

The INA254 features a precision, 400- $\mu\Omega$ current-sensing resistor and supports common-mode voltages up to 80 V. The internal amplifier features a precision zero-drift topology with excellent common-mode rejection ratio (CMRR). The internal amplifier also features an enhanced pulse-width modulation (PWM) rejection current-sensing amplifier integrated into a single package. High-precision measurements are enabled by matching the shunt resistor value and the current-sensing amplifier gain, thus providing a highly-accurate, system-calibrated method for measuring current. Enhanced PWM rejection reduces the effect of common-mode transients on the output signal that are associated with PWM signals. Multiple gain versions are available to allow for the optimization of the desired full-scale output voltage based on the target current range expected in the application.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Integrated Shunt Resistor

The INA254 features a precise, low-drift, current-sensing resistor that provides accurate measurements over the entire specified temperature range of -40°C to $+125^{\circ}\text{C}$. The integrated current-sensing resistor provides measurement stability over temperature, and simplifies printed circuit board (PCB) layout and board constraint difficulties common in high-precision measurements.

The onboard current-sensing resistor is designed as a 4-wire (or Kelvin) connected resistor that enables accurate measurements through a force-sense connection. Connecting the amplifier input pins (IN $-$ and IN $+$) to the sense pins of the shunt resistor (SH $-$ and SH $+$) eliminates many instances of parasitic impedance commonly found in typical very-low sensing-resistor level measurements. Although the sense connection of the current-sensing resistor can be accessed through the SH $+$ and SH $-$ pins, this resistor is not intended to be used as a stand-alone component. The INA254 is system-calibrated to make sure that the current-sensing resistor and current-sensing amplifier are both precisely matched to one another. Use of the shunt resistor without the onboard amplifier results in a current-sensing resistor tolerance of approximately 5%. To achieve the optimized system gain specification, the onboard sensing resistor must be used with the internal current-sensing amplifier.

The INA254 has approximately 1 m Ω of package resistance. Of this total package resistance, 400 $\mu\Omega$ is a precisely-controlled resistance from the Kelvin-connected current-sensing resistor used by the amplifier. The power dissipation requirements of the system and package are based on the total 1-m Ω package resistance between the IS $+$ and IS $-$ pins. The heat dissipated across the package when current flows through the device ultimately determines the maximum current that can be safely handled by the package. The current consumption of the silicon is relatively low, leaving the total package resistance to carry the high load current as the primary contributor to the total power dissipation of the package. The maximum safe-operating current level is set to make sure that the heat dissipated across the package is limited so that no damage occurs to the resistor or the package, or that the internal junction temperature of the silicon does not exceed a 150°C limit.

External factors, such as ambient temperature, external air flow, and PCB layout, contribute to how effectively the device dissipates heat. The internal heat is developed as a result of the current flowing through the total package resistance of 1 m Ω . Under the conditions of no air flow, a maximum ambient temperature of 85°C , and

2-oz. copper input power planes, the INA254 accommodates continuous current levels up to 50 A. [Figure 8-1](#) shows that the current-handling capability is derated at temperatures greater than the 85°C level, with safe operation up to 30 A at a 125°C ambient temperature. With air flow and larger 2-oz. copper input power planes, the INA254 safely accommodates continuous current levels up to 50 A across the entire –40°C to +125°C temperature range.

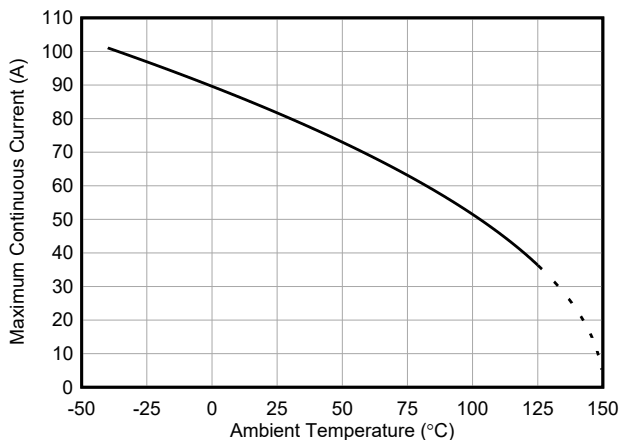


Figure 8-1. Maximum Continuous Current vs Ambient Temperature

8.3.2 Short-Circuit Duration

The INA254 features a physical shunt resistance that is able to withstand current levels higher than the continuous handling limit of 50 A without sustaining damage to the current-sensing resistor or the current-sensing amplifier, if the excursions are brief. [Figure 8-2](#) shows the short-circuit duration curve for the INA254.

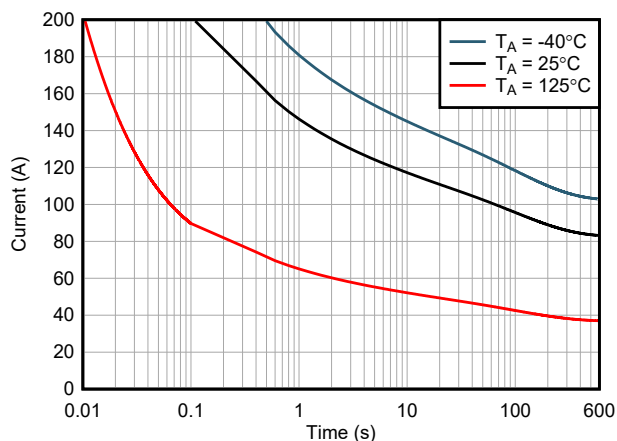


Figure 8-2. Short-Circuit Duration

8.3.3 Temperature Stability

System calibration is common for many industrial applications to eliminate initial component and system-level errors that can be present. A system-level calibration reduces the initial accuracy requirement for many of the individual components because the errors associated with these components are effectively eliminated through the calibration procedure. This calibration enables precise measurements at the temperature in which the system is calibrated. As the system temperature changes because of external ambient changes or self heating, measurement errors are reintroduced. Without accurate temperature compensation used in addition to the initial adjustment, the calibration procedure is not effective. The user must account for temperature-induced changes. One of the primary benefits of the low temperature coefficient of the INA254 (including both the integrated current-sensing resistor and current-sensing amplifier) is that the device measurement remains accurate, even when the temperature changes throughout the specified temperature range of the device.

Figure 8-3 shows the drift performance for the integrated current-sensing resistor. Use Figure 8-3 to determine the typical variance in the shunt resistor value at various temperatures. As with any resistive element, the tolerance of the component varies when exposed to different temperature conditions. For the current-sensing resistor integrated in the INA254, the resistor does vary slightly more when operated in temperatures ranging from -40°C to 0°C than when operated from 0°C to 125°C .

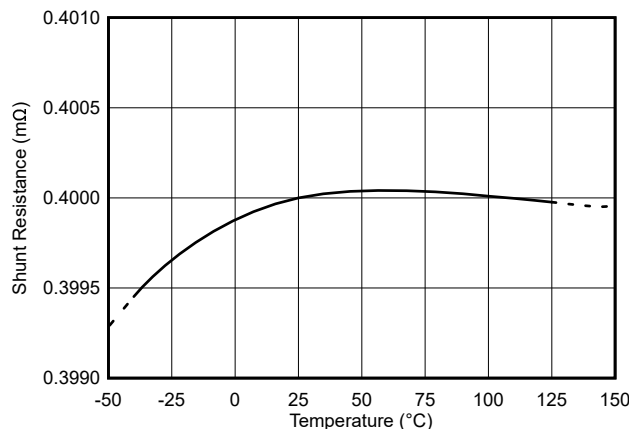


Figure 8-3. Sensing Resistor vs Temperature

An additional aspect to consider is that when current flows through the current-sensing resistor, power is dissipated across this component. This dissipated power results in an increase in the internal temperature of the package, including the integrated sensing resistor. This resistor self-heating effect results in an increase of the resistor temperature helping to move the component out of the colder, wider drift temperature region.

8.3.4 Enhanced PWM Rejection Operation

The enhanced PWM rejection feature of the INA254 provides increased attenuation of large common-mode $\Delta V/\Delta t$ transients. Large $\Delta V/\Delta t$ common-mode transients associated with PWM signals are employed in applications such as motor or solenoid drive and switching power supplies. Traditionally, large $\Delta V/\Delta t$ common-mode transitions are handled strictly by increasing the amplifier signal bandwidth, which can increase chip size, complexity and ultimately cost. The INA254 is designed with high common-mode rejection techniques to reduce large $\Delta V/\Delta t$ transients before the system is disturbed as a result of these large signals. The high AC CMRR, in conjunction with signal bandwidth, allows the INA254 to provide minimal output transients and ringing compared with standard circuit approaches.

8.3.5 Input Signal Bandwidth

The INA254 input signal, which represents the current being measured, is accurately measured with minimal disturbance from large $\Delta V/\Delta t$ common-mode transients as previously described. For PWM signals typically associated with motors, solenoids, and other switching applications, the current being monitored varies at a significantly slower rate than the faster PWM frequency.

The INA254 bandwidth is defined by the -3-dB bandwidth of the current-sense amplifier inside the device. The device bandwidth provides fast throughput and fast response required for the rapid detection and processing of overcurrent events. Without the higher bandwidth, protection circuitry may not have adequate response time, and damage may occur to the monitored application or circuit.

Figure 8-4 shows the performance profile of the device over frequency. Harmonic distortion increases at the upper end of the amplifier bandwidth with no adverse change in detection of overcurrent events. However, increased distortion at the highest frequencies must be considered when the measured current bandwidth begins to approach the INA254 bandwidth.

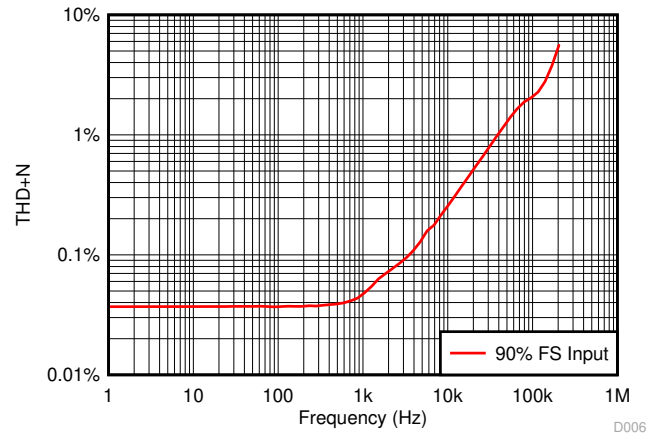


FIG 8-4. Amplifier Performance Over Frequency

For applications requiring distortion sensitive signals, [FIG 8-4](#) provides information to show that there is an optimal frequency performance range for the amplifier. The full amplifier bandwidth is always available for fast overcurrent events at the same time that the lower-frequency signals are amplified at a low distortion level. The output signal accuracy is reduced for frequencies closer to the maximum bandwidth. Individual requirements determine the acceptable limits of distortion for high-frequency, current-sensing applications. Testing and evaluation in the end application or circuit are required to determine the acceptance criteria, and to validate the performance levels meet the system specifications.

8.4 Device Functional Modes

8.4.1 Adjusting the Output Midpoint With the Reference Pins

Figure 8-5 shows a test circuit for reference-divider accuracy. The INA254 output is configurable to allow for unidirectional or bidirectional operation.

注意

Do not connect the REF1 pin or the REF2 pin to any voltage source lower than GND or higher than the supply voltage V_S .

The output voltage is set by applying a voltage or voltages to the reference voltage inputs, REF1 and REF2. The reference inputs are connected to an internal gain network. There is no operational difference between the two reference pins.

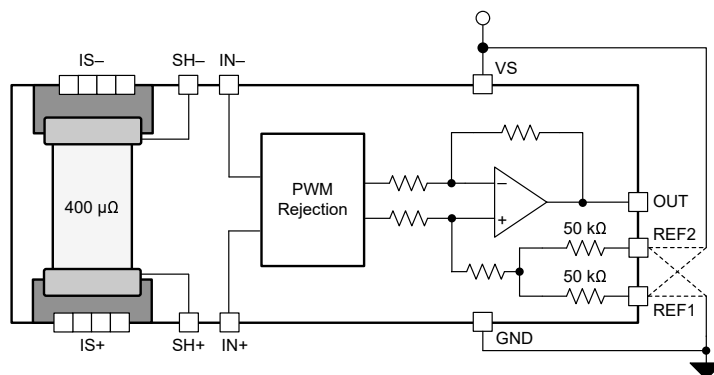


Figure 8-5. Adjusting the Output Midpoint

8.4.2 Reference Pin Connections for Unidirectional Current Measurements

Unidirectional operation allows current measurements through a resistive shunt in one direction. For unidirectional operation, connect the device reference pins together and then to the negative rail (see the [Ground Referenced Output](#) section). The required differential input polarity depends on the output voltage setting. The amplifier output moves away from the referenced rail proportional to the current passing through the internal shunt resistor.

8.4.3 Ground Referenced Output

When using the INA254 in unidirectional mode with a ground-referenced output, both reference inputs are connected to ground. Figure 8-6 shows how this configuration takes the output to ground when there is 0 A flowing across the internal shunt.

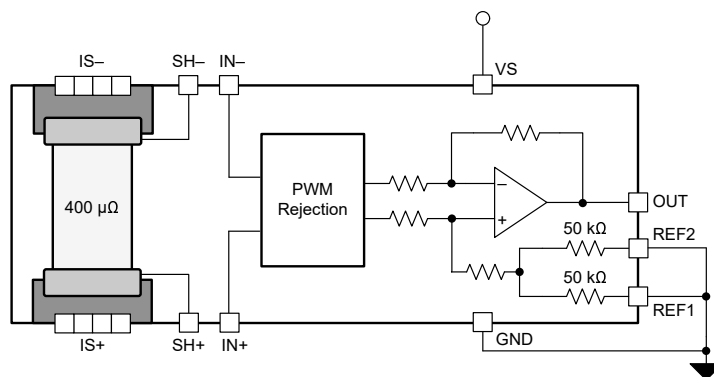


Figure 8-6. Ground-Referenced Output

8.4.4 Reference Pin Connections for Bidirectional Current Measurements

Bidirectional operation allows the INA254 to measure currents through a resistive shunt in two directions. For this case, set the output voltage anywhere within the reference input limits. A common configuration is to set the reference inputs at half-scale for equal range in both directions. However, the reference inputs can be set to a voltage other than half-scale when the bidirectional current is nonsymmetrical.

8.4.4.1 Output Set to External Reference Voltage

Connecting both pins together and then to a reference voltage results in an output voltage equal to the reference voltage for the condition of shorted input pins or a 0-V differential input. [Figure 8-7](#) shows this configuration. The output voltage decreases below the reference voltage when the IN+ pin is negative relative to the IN– pin, and increases when the IN+ pin is positive relative to the IN– pin. This technique is the most accurate way to bias the output to a precise voltage.

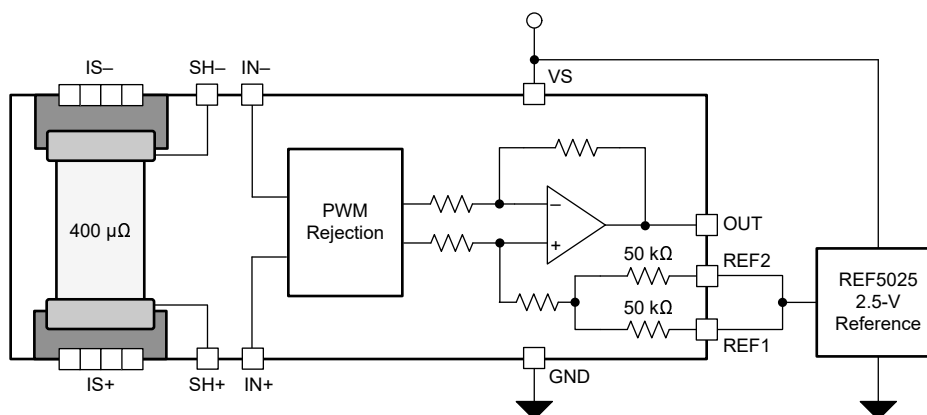


Figure 8-7. External Reference Output

8.4.5 Output Set to Mid-Supply Voltage

[Figure 8-8](#) shows that, by connecting one reference pin to VS and the other to the GND pin, the output is set at half of the supply when there is no differential input. This method creates a ratiometric offset to the supply voltage, where the output voltage remains at $VS / 2$ when 0 V is applied between the IN+ and IN– inputs.

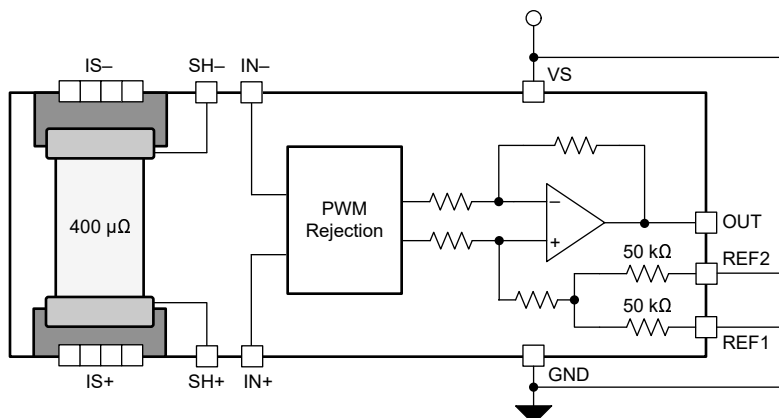


Figure 8-8. Mid-Supply Voltage Output

8.4.6 Output Set to Mid-External Reference

In this example, [Figure 8-9](#) shows how an external reference is divided by two by connecting one REF pin to ground and the other REF pin to the reference.

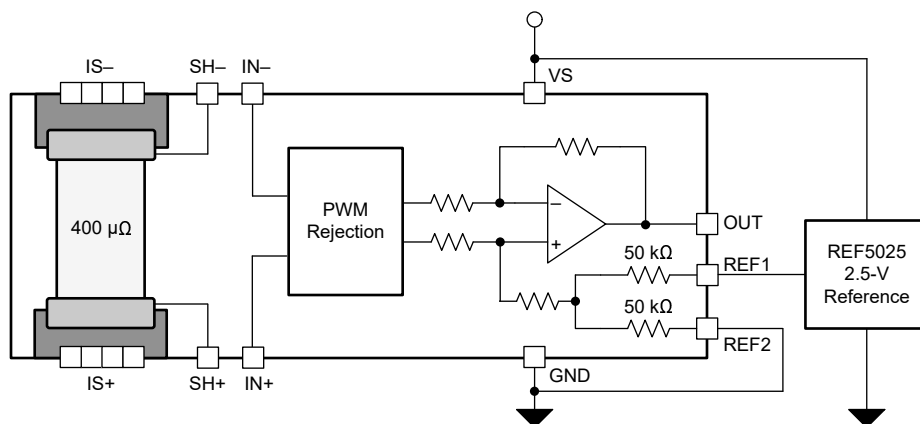


Figure 8-9. Mid-External Reference Output

8.4.7 Output Set Using Resistor Divider

The INA254 REF1 and REF2 pins allow for the midpoint of the output voltage to be adjusted for system circuitry connections to analog to digital converters (ADCs) or other amplifiers. The REF pins are designed to be connected directly to supply, ground, or a low-impedance reference voltage. The REF pins can be connected together and biased using a resistor divider to achieve a custom output voltage. If the amplifier is used in this configuration, like in [Figure 8-10](#), use the output as a differential signal with respect to the resistor divider voltage. For most accurate results, do not use single-ended measurements at the amplifier output because the internal impedance shifts can adversely affect device performance specifications.

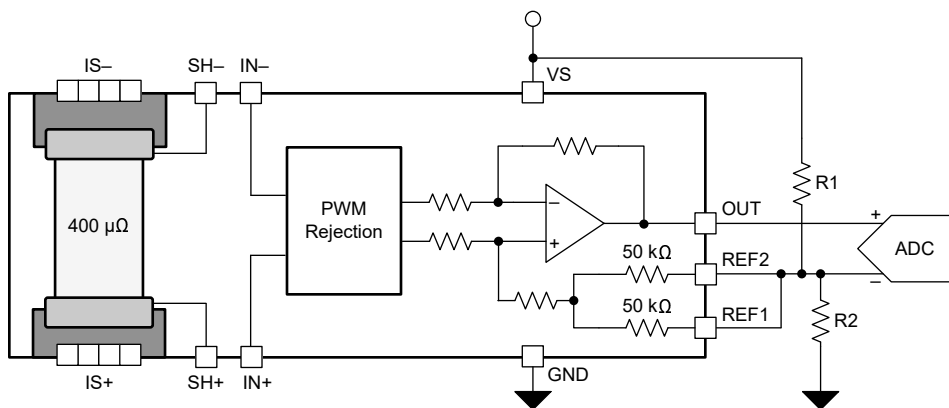


Figure 8-10. Setting the Reference Using a Resistor Divider

9 Application and Implementation

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

9.1 Application Information

The INA254 measures the voltage developed as current flows across the integrated low inductive current-sensing resistor. The device provides reference pins to configure operation as either unidirectional or bidirectional output swing. When using the INA254 for inline motor current sense or measuring current in an H-bridge, the device is commonly configured for bidirectional operation.

9.1.1 Input Filtering

注

Input filters are not required for accurate measurements using the INA254. For most accurate results, do not use filters at the IN+ and IN– inputs. However, If filter components are used on the input of the amplifier, follow the guidelines in this section to minimize effects on performance.

Based strictly on user design requirements, external filtering of the current signal may be desired. The initial location that can be considered for the filter is at the output of the current amplifier. Although placing the filter at the output satisfies the filtering requirements, this location changes the low output impedance measured by any circuitry connected to the output voltage pin. The other location for filter placement is at the current amplifier input pins. This location also satisfies the filtering requirement, but carefully select the components to minimize the impact on device performance. [Figure 9-1](#) shows a filter placed at the inputs pins.

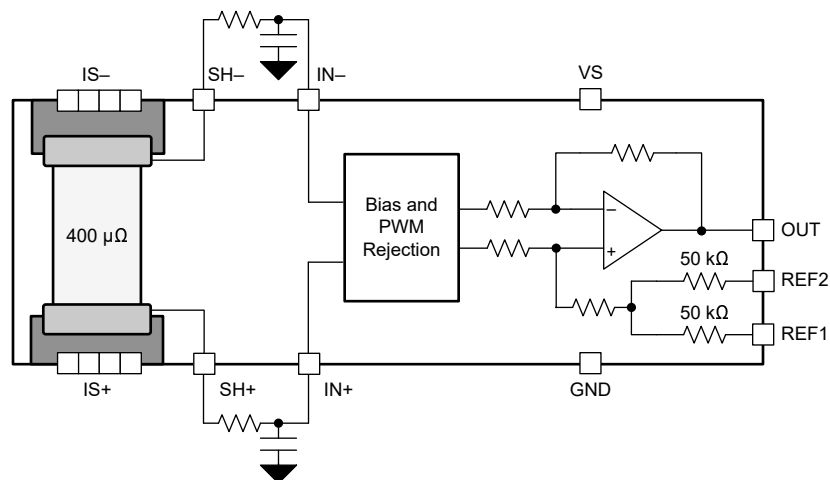


Figure 9-1. Filter at Input Pins

External series resistance provides a source of additional measurement error. Therefore, keep the value of these series resistors to 10 Ω or less to reduce loss of accuracy. The internal bias network shown in [Figure 9-1](#) creates a mismatch in input bias currents when a differential voltage is applied between the input pins (see [Figure 9-2](#)). If additional external series filter resistors are added to the circuit, a mismatch is created in the voltage drop across the filter resistors. This voltage is a differential error voltage in the shunt resistor voltage. In addition to the absolute resistor value, mismatch resulting from resistor tolerance can significantly impact the error because this value is calculated based on the actual measured resistance.

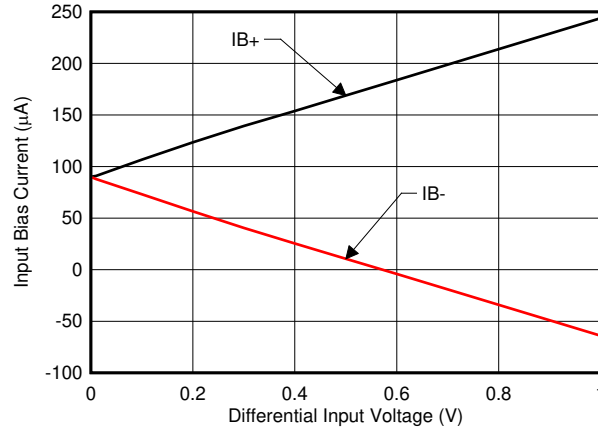


图 9-2. Input Bias Current vs Differential Input Voltage

Use 式 1 to calculate the measurement error expected from the additional external filter resistors.

$$\text{Gain Error (\%)} = 100 - (100 \times \text{Gain Error Factor}) \quad (1)$$

where

- 式 2 determines the Gain Error Factor

$$\text{Gain Error Factor} = \frac{3000}{R_S + 3000} \quad (2)$$

Where:

- R_S is the external filter resistance value

Use 式 2 to calculate the gain error factor and determine the gain error introduced by the additional external series resistance. Use 式 1 to calculate the deviation of the shunt voltage resulting from the attenuation and imbalance created by the added external filter resistance. 表 9-1 provides the gain error factor and gain error for several resistor values.

表 9-1. Gain Error Factor and Gain Error for External Input Resistors

EXTERNAL RESISTANCE (Ω)	GAIN ERROR FACTOR	GAIN ERROR (%)
5	0.998	0.17
10	0.997	0.33
100	0.968	3.23

9.2 Typical Applications

The INA254 offers advantages for multiple applications including the following:

- High common-mode range and excellent CMRR enables direct inline sensing
- Precision low-inductive, low-drift shunt eliminates the need for overtemperature system calibration
- Ultra-low offset and drift eliminates the necessity of calibration
- Wide supply range enables a direct interface with most microprocessors

9.2.1 Speaker Enhancements and Diagnostics Using Current Sense Amplifier

CLASS-D audio amplifiers in conjunction with the INA254 provide accurate speaker load current. Speaker load current is used to determine speaker diagnostics, and can further be expanded to measure key speaker parameters, such as speaker coil resistance and speaker real-time ambient temperature.

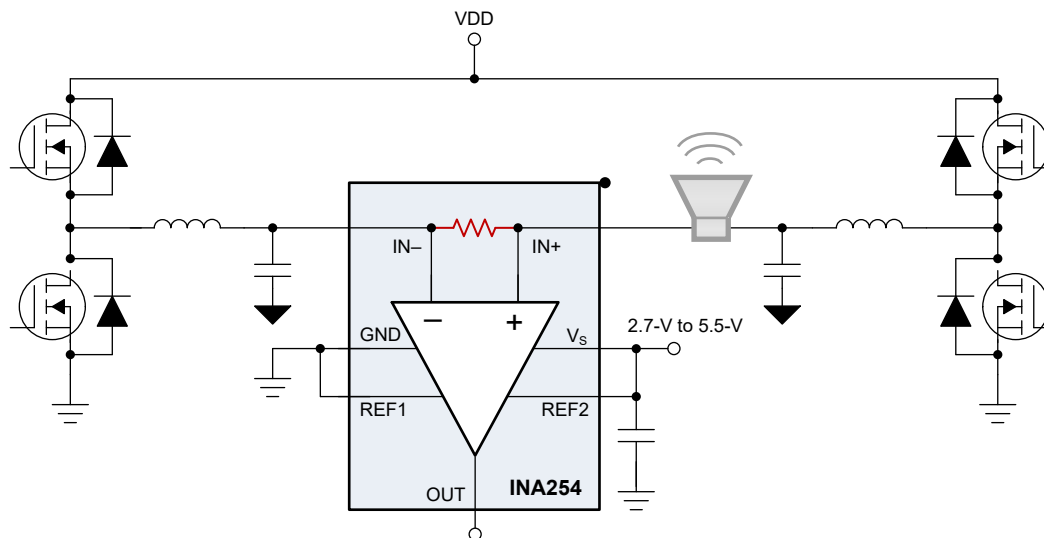


图 9-3. Current Sensing in a CLASS-D Subsystem

9.2.1.1 Design Requirements

表 9-2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Common-mode voltage	60 V
Power-supply voltage	3.3 V
Peak current	±15 A
Frequency sweep	20 Hz to 20 KHz

9.2.1.2 Detailed Design Procedure

For this application, the INA254 measures current flowing through the speaker from the CLASS-D amplifier. The integrated shunt of 400 $\mu\Omega$ with an inductance of only 2 nH is an excellent choice for current sensing in speaker applications where low inductance is required. The low-inductive shunt enables accurate current sensing across frequencies over the audio range of 20 Hz to 20 kHz.

The INA254 is setup to support bidirectional currents with the reference set to mid-supply as shown in 图 8-9. When the power supply to the INA254 is set at 3.3 V and there is no current flowing in the speaker, the output of INA254 is at 1.65 V. When operating with a gain of 75 mV/A with peak-to-peak current of ± 15 A, the output of the INA254 will swing from 0.525 V to 2.775 V. In this application the output can be directly connected to an ADC input that has a full scale range of 3.3 V. The INA254 has a low THD+N of 0.1% at 1 kHz that enables distortion measurement of speaker. The INA254 can measure the impedance of the speaker and accurately measure the resonance frequency and peak impedance at resonance frequency. The INA254 can accurately track changes in the impedance in real-time.

9.2.1.3 Application Curve

Figure 9-4 shows the typical example output response of a speaker with 4-Ω impedance measurement from 20 Hz to 20 kHz.

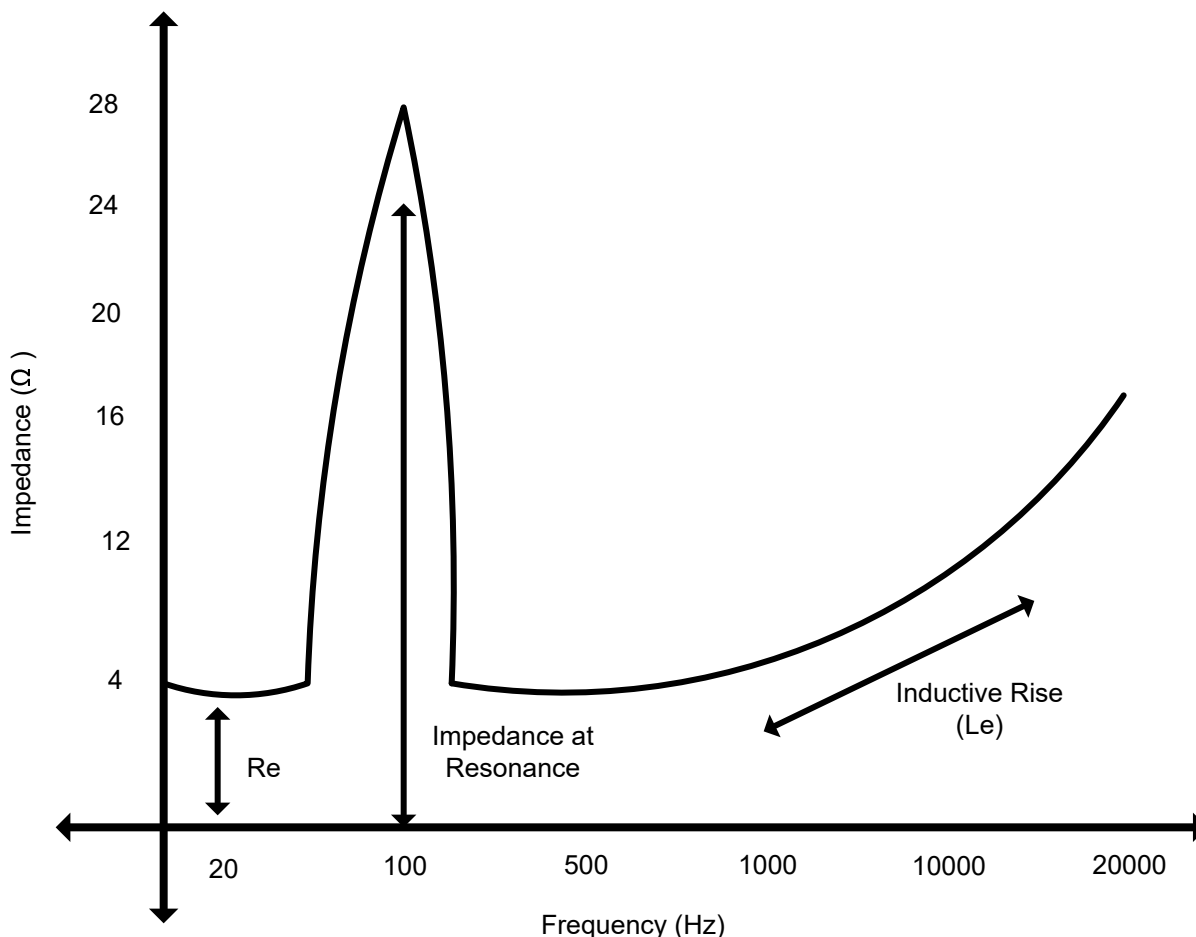


Figure 9-4. Speaker Impedance Measurement

9.3 Power Supply Recommendations

The INA254 makes accurate measurements beyond the connected power-supply voltage (V_S) because the inputs ($IN+$ and $IN-$) operate anywhere between -4 V and $+80$ V, independent of V_S . For example, the V_S power supply equals 5 V and the common-mode voltage of the measured shunt can be as high as 80 V. Although the common-mode voltage of the input can be beyond the supply voltage, the output voltage range of the INA254 is constrained to the supply voltage.

Place the power-supply bypass capacitor as close as possible to the supply and ground pins. The recommended value of this bypass capacitor is 0.1 μ F. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies. If the INA254 output is set to mid-supply, then take extreme care to minimize noise on the power supply.

9.4 Layout

9.4.1 Layout Guidelines

- This device is specified for current handling of up to 50 A over the entire -40°C to $+85^\circ\text{C}$ temperature range using a 2-oz. copper pour for the input power plane, as well as no external airflow passing over the device.

- The primary current-handling limitation for this device is how much heat is dissipated inside the package. Efforts to improve heat transfer out of the package and into the surrounding environment improve the ability of the device to handle currents of up to 50 A over a wider temperature range.
- Heat transfer improvements primarily involve larger copper power traces and planes with increased copper thickness (2 oz.), as well as providing airflow to pass over the device. Thermal vias help spread the current and power dissipated over multiple board layers. The INA254 evaluation module (EVM) features a 2-oz. copper pour for the planes, and is capable of supporting 50 A at temperatures up to 125°C.
- The bypass capacitor should be placed close to device ground and supply pins, but can be moved farther out if needed to avoid cutting thermal planes. The recommended value of this bypass capacitor is 0.1 μ F. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

9.4.2 Layout Example

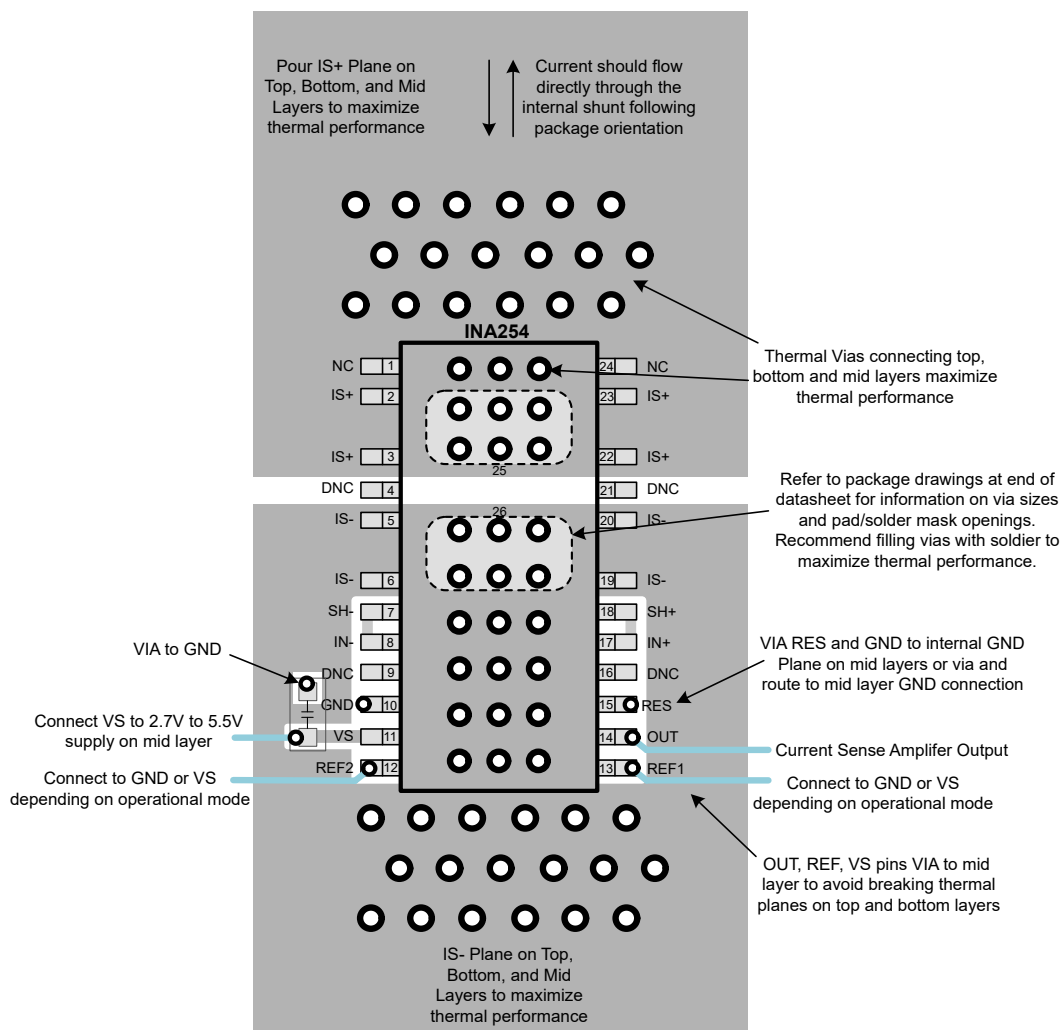


FIG 9-5. INA254 Layout Example

10 Device and Documentation Support

10.1 Device Support

10.1.1 Development Support

For development support, see the [INA254 Evaluation Module \(EVM\)](#).

10.2 Documentation Support

10.2.1 Related Documentation

For related documentation see the following: Texas Instruments, [INA254EVM User's Guide](#) (SLOU514)

10.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](#) のデバイス製品フォルダを開いてください。「更新の通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

10.4 サポート・リソース

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10.7 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA254A1IPWAR	Active	Production	HTSSOP (PWA) 24	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	IN254A1
INA254A1IPWAR.A	Active	Production	HTSSOP (PWA) 24	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	IN254A1
INA254A2IPWAR	Active	Production	HTSSOP (PWA) 24	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	IN254A2
INA254A2IPWAR.A	Active	Production	HTSSOP (PWA) 24	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	IN254A2
INA254A3IPWAR	Active	Production	HTSSOP (PWA) 24	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	IN254A3
INA254A3IPWAR.A	Active	Production	HTSSOP (PWA) 24	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	IN254A3

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

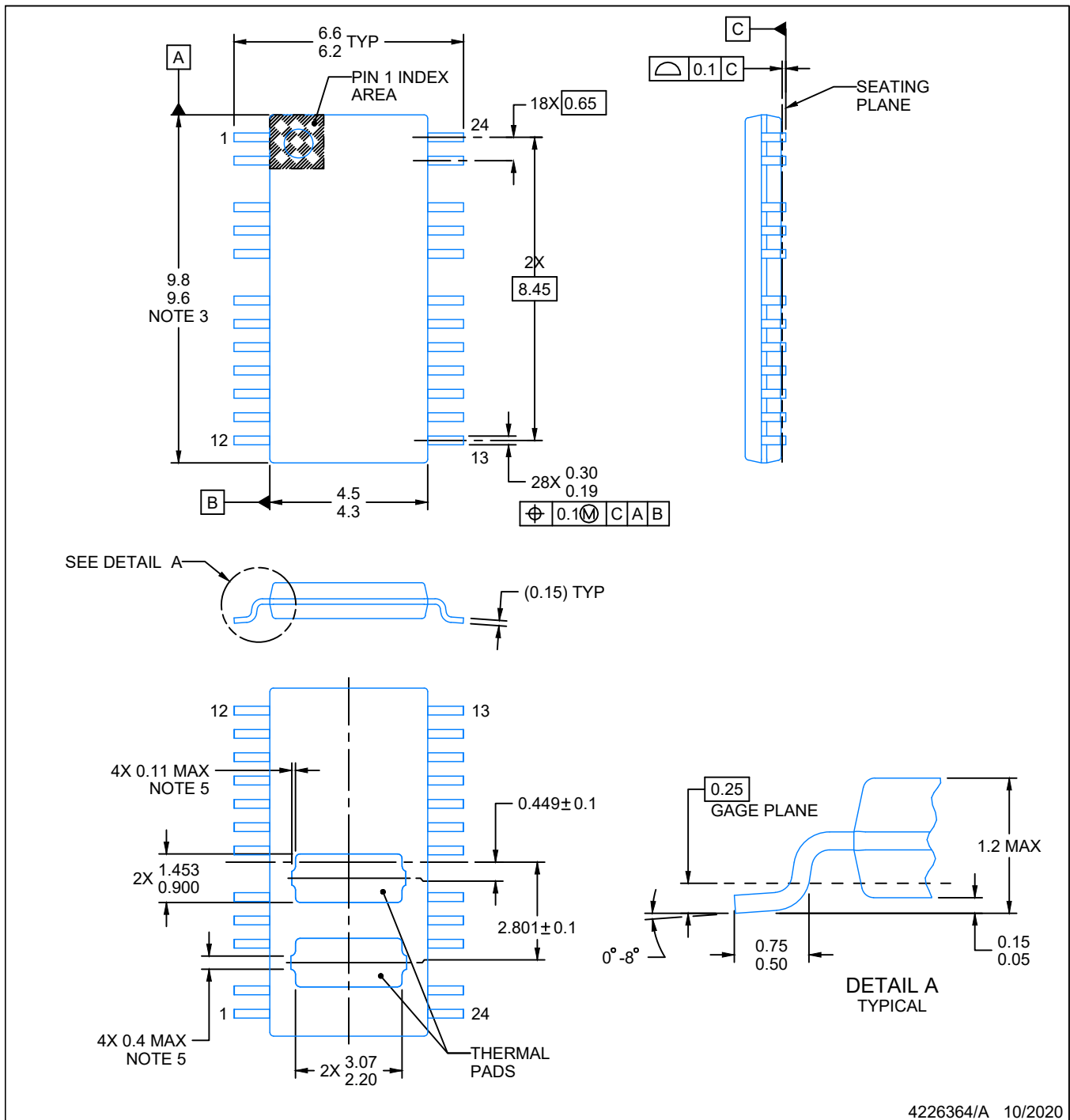
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA254A1IPWAR	HTSSOP	PWA	24	2500	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
INA254A2IPWAR	HTSSOP	PWA	24	2500	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
INA254A3IPWAR	HTSSOP	PWA	24	2500	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA254A1IPWAR	HTSSOP	PWA	24	2500	350.0	350.0	43.0
INA254A2IPWAR	HTSSOP	PWA	24	2500	350.0	350.0	43.0
INA254A3IPWAR	HTSSOP	PWA	24	2500	350.0	350.0	43.0



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NOTES:

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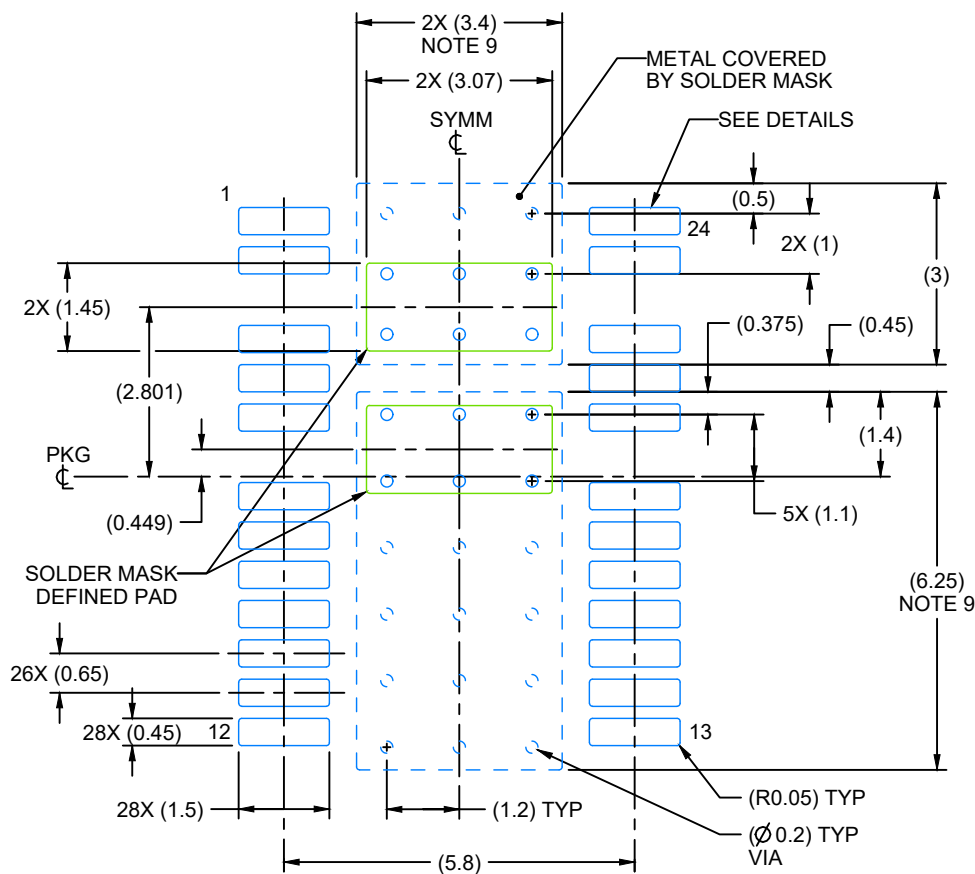
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.
5. Features may differ or may not be present.

EXAMPLE BOARD LAYOUT

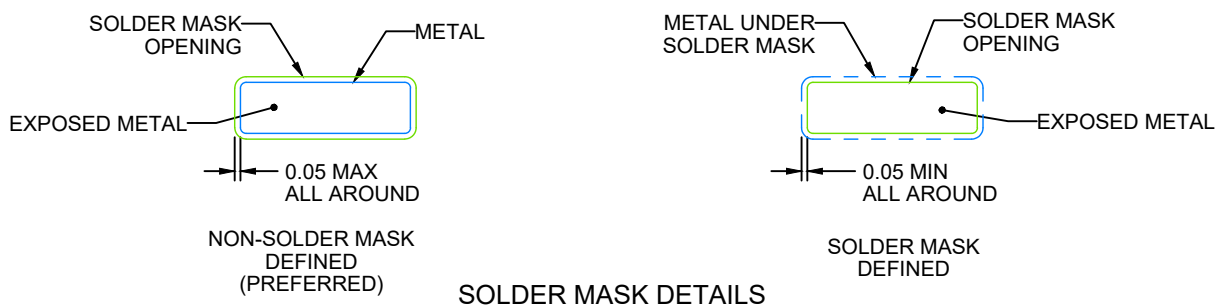
PWA0024A

PowerPAD™ TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 8X



SOLDER MASK DETAILS

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NOTES: (continued)

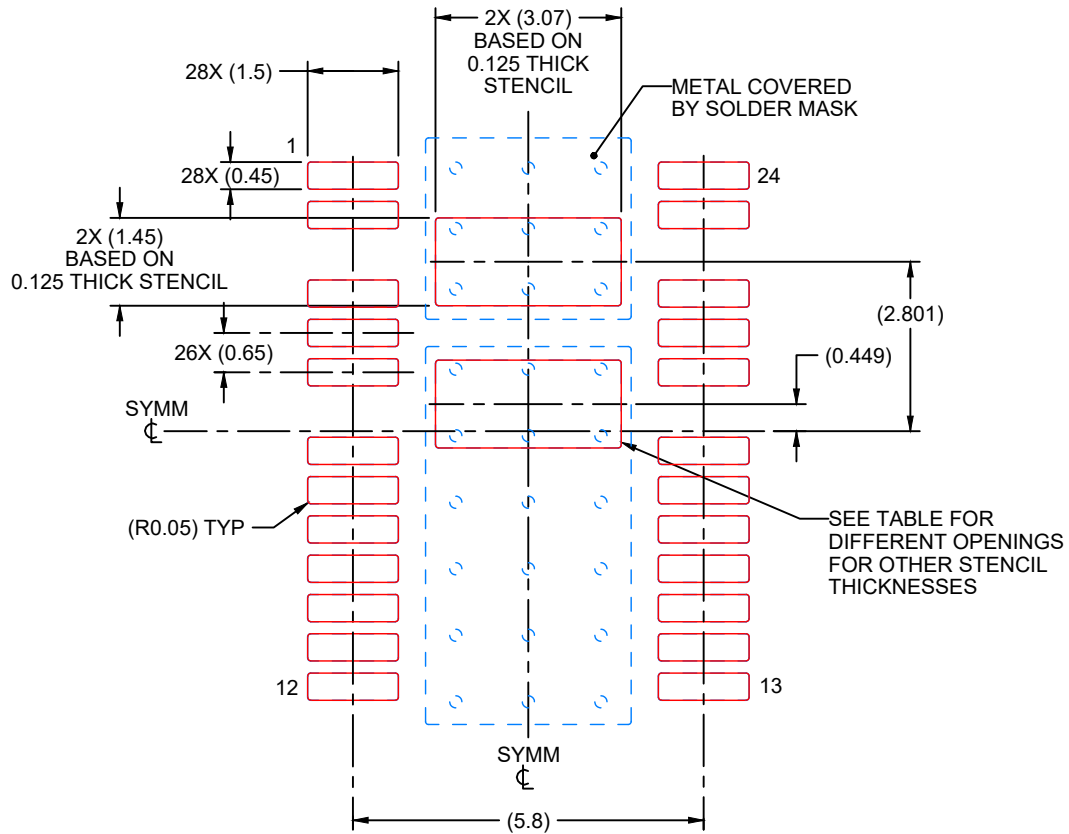
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

PWA0024A

PowerPAD™ TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 8X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.43 X 1.62
0.125	3.07 X 1.45 (SHOWN)
0.15	2.80 X 1.33
0.175	2.59 X 1.23

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NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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